Hex Inverter

High-Performance Silicon-Gate CMOS

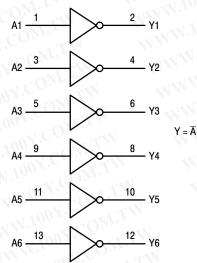
The MC74HC04A is identical in pinout to the LS04 and the MC14069. The device inputs are compatible with Standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

The device consists of six three-stage inverters.

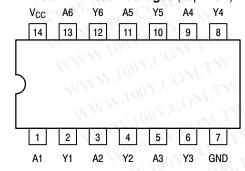
Features

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1 μA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance With the JEDEC Standard No. 7A Requirements
- Chip Complexity: 36 FETs or 9 Equivalent Gates
- Pb-Free Packages are Available*

LOGIC DIAGRAM



Pinout: 14-Lead Packages (Top View)



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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MARKING DIAGRAMS

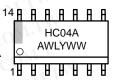


PDIP-14 N SUFFIX CASE 646





SOIC-14 D SUFFIX CASE 751A





TSSOP-14 DT SUFFIX CASE 948G 14 HRHHHHH HC 04 • ALYW

A = Assembly Location

WL or L = Wafer Lot YY or Y = Year WW or W = Work Week

FUNCTION TABLE

Inputs	Outputs
Α	Υ 10
MIT	H. M.
HV	VEN .

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787

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MAXIMUM RATINGS

1AXIMUM	RATINGS	胜特刀电子(深圳) 86-755-83298 Http://www.100y.com.tw	787
Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V _{in}	DC Input Voltage (Referenced to GND)	- 0.5 to V _{CC} + 0.5	V
V _{out}	DC Output Voltage (Referenced to GND)	- 0.5 to V _{CC} + 0.5	V
l _{in}	DC Input Current, per Pin	± 20	mA
l _{out}	DC Output Current, per Pin	± 25	mA
Icc	DC Supply Current, V _{CC} and GND Pins	± 50	mA
P_{D}	Power Dissipation in Still Air, Plastic DIP† SOIC Package† TSSOP Package†	750 500 450	mW
T _{stg}	Storage Temperature	- 65 to + 150	°C
Y.TON	Lead Temperature, 1 mm from Case for 10 Seconds Plastic DIP, SOIC or TSSOP Package	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied,

†Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C

SOIC Package: - 7 mW/°C from 65° to 125°C

SOIC Package: – 7 mW/°C from 65° to 125°C
TSSOP Package: – 6.1 mW/°C from 65° to 125°C
For high frequency or heavy load considerations, see Chapter 2 of the ON Semiconductor High–Speed CMOS Data Book (DL129/D).

RECOMMENDED OPERATING CONDITIONS

Symbol	DOX. CONTIAN	Min	Max	Unit	
V _{CC}	DC Supply Voltage (Referenced to	2.0	6.0	V	
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Referenced to GND)			V _{CC}	V
T _A	Operating Temperature, All Package Types		- 55	+ 125	°C
t _r , t _f	Input Rise and Fall Time (Figure 1)	$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$	0 0 0	1000 500 400	ns

ORDERING INFORMATION

Device Order Number	Package	Shipping [†]
MC74HC04AN	PDIP-14	2000 / Rail
MC74HC04ANG	PDIP-14 (Pb-Free)	2000 / Rail
MC74HC04AD	SOIC-14	55 / Rail
MC74HC04ADG	SOIC-14 (Pb-Free)	55 / Rail
MC74HC04ADR2	SOIC-14	2500 / Tape & Reel
MC74HC04ADR2G	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC74HC04ADTR2	TSSOP-14*	2500 / Tape & Reel
MC74HC04AF	SOEIAJ-14	50 / Rail
MC74HC04AFG	SOEIAJ-14 (Pb-Free)	50 / Rail
MC74HC04AFEL	SOEIAJ-14	2000 / Tape & Reel
MC74HC04AFELG	SOEIAJ-14 (Pb-Free)	2000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

damage may occur and reliability may be affected.
*This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, Vin and V_{out} should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC} . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

^{*}This package is inherently Pb-Free.

DC CHARACTERISTICS (Voltages Referenced to GND)

	MMM. COM	YWW WIT	v _{cc}	Guaranteed Limit			
Symbol	Parameter	Condition		-55 to 25°C	≤85°C	≤125°C	Unit
V _{IH}	Minimum High-Level Input Voltage	$V_{out} = 0.1 V \text{ or } V_{CC} - 0.1 V$ $ I_{out} \le 20 \mu A$	2.0 3.0 4.5 6.0	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	V
V _{IL} TV	Maximum Low–Level Input Voltage	$V_{out} = 0.1 V \text{ or } V_{CC} - 0.1 V$ $ I_{out} \le 20 \mu A$	2.0 3.0 4.5 6.0	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	V
V _{OH}	Minimum High-Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 20 \mu A$	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
	M.TW WWW.I	$\begin{split} V_{in} = & V_{IH} \text{ or } V_{IL} & I_{out} \leq 2.4 \text{mA} \\ & I_{out} \leq 4.0 \text{mA} \\ & I_{out} \leq 5.2 \text{mA} \end{split}$	3.0 4.5 6.0	2.48 3.98 5.48	2.34 3.84 5.34	2.20 3.70 5.20	
V _{OL}	Maximum Low–Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 20 \mu A$	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
	CON.TW WY	$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 2.4 \text{mA}$ $ I_{out} \le 4.0 \text{mA}$ $ I_{out} \le 5.2 \text{mA}$	3.0 4.5 6.0	0.26 0.26 0.26	0.33 0.33 0.33	0.40 0.40 0.40	
l _{in} .100	Maximum Input Leakage Current	V _{in} = V _{CC} or GND	6.0	± 0.1	± 1.0	± 1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC}$ or GND $I_{out} = 0\mu A$	6.0	1.0	10	40	μΑ

NOTE: Information on typical parametric values can be found in Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

AC CHARACTERISTICS ($C_L = 50pF$, Input $t_f = t_f = 6ns$)

WIX	N.TO COM.		Guaranteed Limit			
Symbol	Parameter	V _{CC}	−55 to 25°C	≤85°C	≤125°C	Unit
t _{PLH} ,	Maximum Propagation Delay, Input A or B to Output Y	2.0	75	95	110	ns
t _{PHL}	(Figures 1 and 2)	3.0	30	40	55	1 -1
	M.In. COM.	4.5	15	19	22	CO_{λ_0}
	M. 100X.COM.TW W. 100	6.0	13	16	19	c01
t _{TLH} ,	Maximum Output Transition Time, Any Output	2.0	75	95	110	ns
t _{THL}	(Figures 1 and 2)	3.0	27	32	36	J C
··· -	WWW. CON.CO THE WAY	4.5	15	19	22	7.
	TAM. TO COM.	6.0	13	16	19	MY.C
C _{in}	Maximum Input Capacitance	Jan.	10	10	10	pF

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

	WWW. 100Y.CO.T.TW	Typical @ 25°C, V _{CC} = 5.0 V	1700
C _{PD}	Power Dissipation Capacitance (Per Inverter)*	20	pF

^{*} Used to determine the no–load dynamic power consumption: $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$. For load considerations, see Chapter 2 of the ON Semiconductor High–Speed CMOS Data Book (DL129/D).

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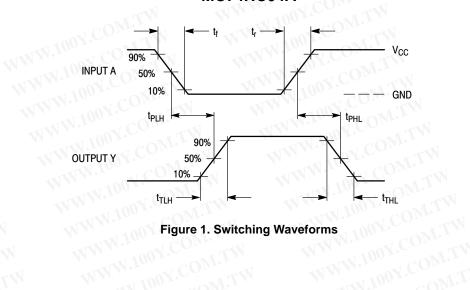
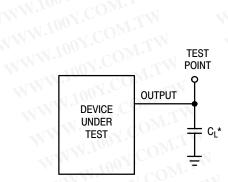


Figure 1. Switching Waveforms WWW.100Y.COM.TW



*Includes all probe and jig capacitance

Figure 2. Test Circuit WWW.100Y.COM.TW

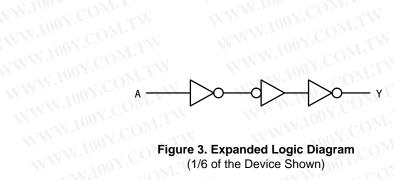


Figure 3. Expanded Logic Diagram WWW.100Y.COM.TW WWW.100Y.COM. (1/6 of the Device Shown)

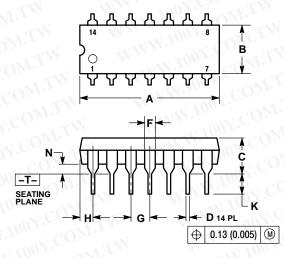
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WW.100X

PACKAGE DIMENSIONS

PDIP-14 **N SUFFIX** CASE 646-06 ISSUE N

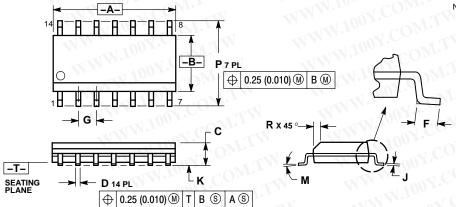




- WW.100Y.COM NOTES:
 1. DIMENSIONING AND TOLERANCING
 - PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 - DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 3.
 - 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 - 5. ROUNDED CORNERS OPTIONAL.

-7	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	18.80	
В	0.240	0.260	6.10	6.60	
O	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100	BSC	2.54	BSC	
Н	0.052	0.095	1.32	2.41	
L	0.008	0.015	0.20	0.38	
Κ	0.115	0.135	2.92	3.43	
Г	0.290	0.310	7.37	7.87	
M	100	10 °	775	10 °	
Z	0.015	0.039	0.38	1.01	

SOIC-14 **D SUFFIX** CASE 751A-03 **ISSUE G**



WWW.100Y

NOTES:

- ANTES.

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

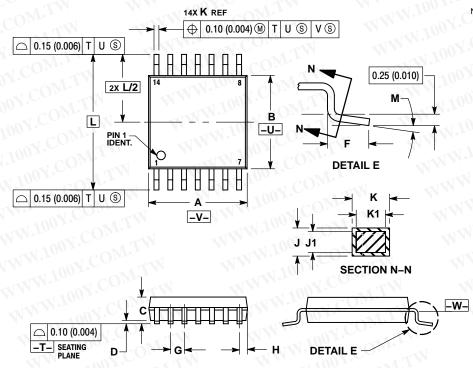
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	8.55	8.75	0.337	0.344
В	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050	BSC
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7°	0 °	7°
Р	5.80	6.20	0.228	0.244
	0.25	0.50	0.010	0.019

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PACKAGE DIMENSIONS

TSSOP-14 **DT SUFFIX** CASE 948G-01 **ISSUE A**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ANSI Y14.5M, 1982.

 CONTROLLING DIMENSION: MILLIMETER.

 J. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
 - MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DOES NOT INCLUDE
 - DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
 - TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 - 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

DIM		IETERS	INC	HES	
•	MIN	MAX	MIN	MAX	
Α.	4.90	5.10	0.193	0.200	
В	4.30	4.50	0.169	0.177	
С		1.20	7 =	0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026 BSC		
H	0.50	0.60	0.020	0.024	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40		0.252	BSC	
M	0 °	8 °	0 °	8 °	

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